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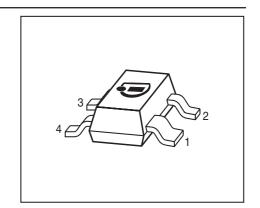






Low Noise Silicon Bipolar RF Transistor

- For low noise, high-gain broadband amplifiers at collector currents from 2 mA to 30 mA
- f_T = 8 GHz, NF_{min} = 0.9 dB at 900 MHz
- Pb-free (RoHS compliant) package
- Qualification report according to AEC-Q101 available





ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration					Package	
BFP183	RHs	1=C	2=E	3=B	4=E	-	ı	SOT143

Maximum Ratings at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{\sf CEO}$	12	V
Collector-emitter voltage	V_{CES}	20	
Collector-base voltage	V_{CBO}	20	
Emitter-base voltage	V_{EBO}	2	
Collector current	I _C	65	mA
Base current	I_{B}	5	
Total power dissipation ¹⁾	P_{tot}	250	mW
<i>T</i> _S ≤ 76 °C			
Junction temperature	T_{J}	150	°C
Storage temperature	T_{Stq}	-55 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ²⁾	R _{thJS}	295	K/W

 $^{{}^{1}}T_{\rm S}$ is measured on the collector lead at the soldering point to the pcb

 $^{^2}$ For the definition of R_{thJS} please refer to Application Note AN077 (Thermal Resistance Calculation)



Electrical Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics	•			•	
Collector-emitter breakdown voltage	V _{(BR)CEO}	12	-	_	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0	, ,				
Collector-emitter cutoff current	I _{CES}	-	-	100	μΑ
$V_{CE} = 20 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I _{CBO}	-	-	100	nA
$V_{\rm CB} = 10 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I _{EBO}	-	_	1	μΑ
$V_{\rm EB} = 1 \text{ V}, I_{\rm C} = 0$					
DC current gain	h _{FE}	70	100	140	_
$I_{\rm C}$ = 15 mA, $V_{\rm CE}$ = 8 V, pulse measured					



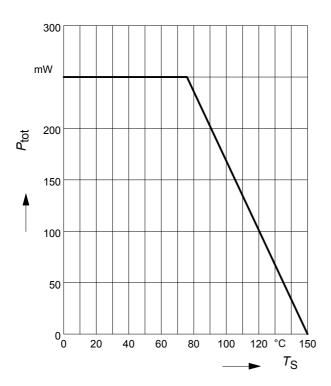
Electrical Characteristics at T_A = 25 °C, unless otherwise specified

Symbol	Values			Unit		
	min.	typ.	max.			
AC Characteristics (verified by random sampling)						
f_{T}	6	8	-	GHz		
C _{cb}	-	0.3	0.5	pF		
C _{ce}	-	0.27	-			
C _{eb}	-	1.1	-			
NF _{min}				dB		
	-	0.9	-			
	-	1.4	_			
G _{ms}	-	22	-	dB		
G _{ma}	-	15.5	-	dB		
$ S_{21e} ^2$				dB		
	_	17.5	_			
	_	11.5	-			
	g) f _T C _{cb} C _{eb} NF _{min} G _{ms}	min. g) f _T 6 6	min. typ. f _T	min. typ. max. f_T 6 8 - C_{cb} - 0.3 0.5 C_{ce} - 0.27 - NF_{min} - 1.1 - G_{ms} - 22 - G_{ma} - 15.5 - $ S_{21e} ^2$ - 17.5 -		

 $^{^{1}}G_{\mathsf{ma}} = |S_{21e} \, / \, S_{12e}| \; (\mathsf{k}\text{-}(\mathsf{k}^{2}\text{-}1)^{1/2}), \; G_{\mathsf{ms}} = |S_{21} \, / \, S_{12}|$

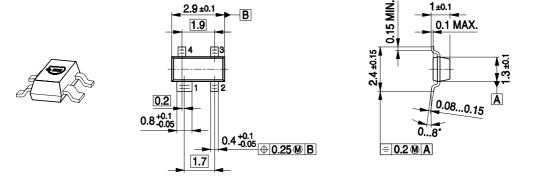


Total power dissipation $P_{\text{tot}} = f(T_{\text{S}})$





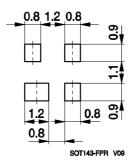
Package Outline



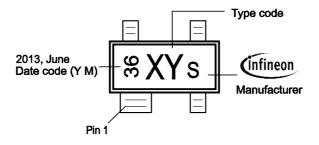
Note: Mold flash, protrusions or gate burrs of 0,2 mm max. per side are not included

SOT143-PO V09

Foot Print

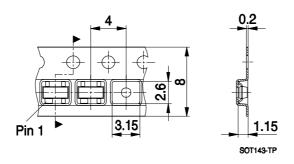


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





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